

Application Data Sheet

Application Information

| | |
|----------------------------------|---|
| Application Type:: | Regular |
| Subject Matter:: | Utility |
| Suggested Group Art Unit:: | Not Yet Assigned |
| CD-ROM or CD-R?:: | None |
| Sequence submission?:: | None |
| Computer Readable Form (CRF)?:: | No |
| Title:: | ELECTRODE EMPLOYING NITRIDE- BASED SEMICONDUCTOR OF III-V GROUP COMPOUND, AND PRODUCING METHOD THEREOF |
| Attorney Docket Number:: | 245402008300 |
| Request for Early Publication?:: | No |
| Request for Non-Publication?:: | No |
| Total Drawing Sheets:: | 4 |
| Small Entity?:: | No |
| Petition included?:: | No |
| Secrecy Order in Parent Appl.?:: | No |

Applicant Information

| | |
|--|--|
| Applicant Authority Type:: | Inventor |
| Primary Citizenship Country:: | Japan |
| Status:: | Full Capacity |
| Given Name:: | Nobuaki |
| Family Name:: | TERAGUCHI |
| City of Residence:: | Oji-cho |
| Country of Residence:: | Japan |
| Street of mailing address:: | 2-1-1-304, Katsushimo, Kitakatsuragi-gun |
| City of mailing address:: | Oji-cho |
| State or Province of mailing address:: | Nara |

Country of mailing address:: Japan

Correspondence Information

Correspondence Customer Number:: 25226

Representative Information

Representative Customer Number:: 25226

Foreign Priority Information

| Country:: | Application number:: | Filing Date:: | Priority Claimed:: |
|-----------|----------------------|---------------|--------------------|
| Japan | 2003-047701 | 02/25/03 | Yes |

Assignee Information

Assignee name:: SHARP KABUSHIKI KAISHA
Street of mailing address:: 22-22, Nagaike-cho, Abeno-ku
City of mailing address:: Osaka-shi
State or Province of mailing address:: Osaka
Country of mailing address:: Japan